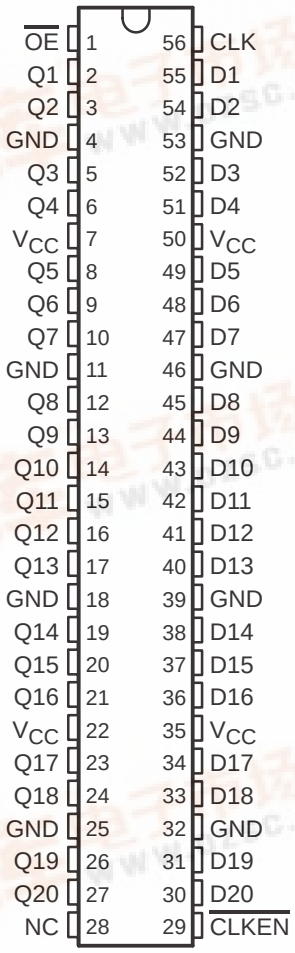
查询SN74ALVCH16721供应商 捷多邦，专业PCB打样工厂，24小时加急出货



- **Member of the Texas Instruments *Widebus*™ Family**
- ***EPIC*™ (Enhanced-Performance Implanted CMOS) Submicron Process**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors**
- **Package Options Include Plastic 300-mil Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), and Thin Very Small-Outline (DGV) Packages**

**DGG, DGV, OR DL PACKAGE**
**(TOP VIEW)**




NC – No internal connection

## description

This 20-bit flip-flop is designed specifically for 1.65-V to 3.6-V $V_{CC}$ operation.

The 20 flip-flops of the SN74ALVCH16721 are edge-triggered D-type flip-flops with qualified clock storage. On the positive transition of the clock (CLK) input, the device provides true data at the Q outputs if the clock-enable ($\overline{CLKEN}$) input is low. If $\overline{CLKEN}$ is high, no data is stored.

A buffered output-enable ($\overline{OE}$) input places the 20 outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components. $\overline{OE}$ does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to $V_{CC}$ through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH16721 is characterized for operation from –40°C to 85°C.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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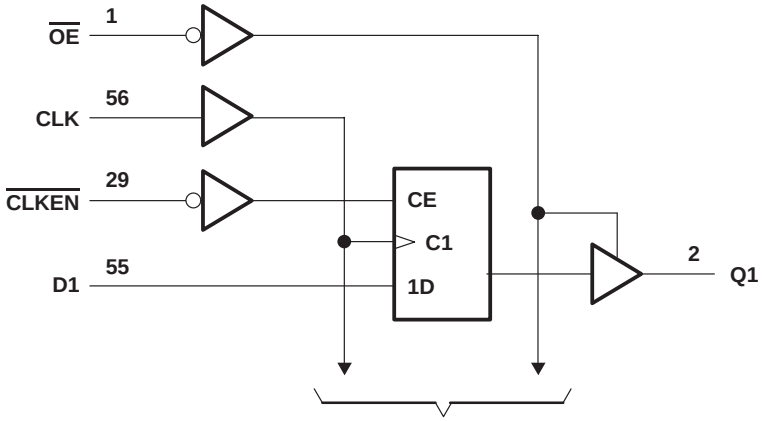
**FUNCTION TABLE**
**(each flip-flop)**

| INPUTS | | | | OUTPUT |
|---|---|---|---|---|
| $\overline{OE}$ | $\overline{CLKEN}$ | CLK | D | Q |
| L | H | X | X | $Q_0$ |
| L | L | ↑ | H | H |
| L | L | ↑ | L | L |
| L | L | L or H | X | $Q_0$ |
| H | X | X | X | Z |

## logic diagram (positive logic)




## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, $V_{CC}$ . . . . . –0.5 V to 4.6 V
Input voltage range, $V_I$ (see Note 1) . . . . . –0.5 V to 4.6 V
Output voltage range, $V_O$ (see Notes 1 and 2) . . . . . –0.5 V to $V_{CC}$ + 0.5 V
Input clamp current, $I_{IK}$ ($V_I$ < 0) . . . . . –50 mA
Output clamp current, $I_{OK}$ ($V_O$ < 0) . . . . . –50 mA
Continuous output current, $I_O$ . . . . . ±50 mA
Continuous current through each $V_{CC}$ or GND . . . . . ±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DGG package . . . . . 81°C/W
DGV package . . . . . 86°C/W
DL package . . . . . 74°C/W
Storage temperature range, $T_{stg}$ . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. This value is limited to 4.6 V maximum.
3. The package thermal impedance is calculated in accordance with JESD 51.

## recommended operating conditions (see Note 4)

| | | | MIN | MAX | UNIT |
|---|---|---|---|---|---|
| $V_{CC}$ | Supply voltage | | 1.65 | 3.6 | V |
| $V_{IH}$ | High-level input voltage | $V_{CC}$ = 1.65 V to 1.95 V | 0.65 × $V_{CC}$ | | V |
| | | $V_{CC}$ = 2.3 V to 2.7 V | 1.7 | | |
| | | $V_{CC}$ = 2.7 V to 3.6 V | 2 | | |
| $V_{IL}$ | Low-level input voltage | $V_{CC}$ = 1.65 V to 1.95 V | | 0.35 × $V_{CC}$ | V |
| | | $V_{CC}$ = 2.3 V to 2.7 V | | 0.7 | |
| | | $V_{CC}$ = 2.7 V to 3.6 V | | 0.8 | |
| $V_I$ | Input voltage | | 0 | $V_{CC}$ | V |
| $V_O$ | Output voltage | | 0 | $V_{CC}$ | V |
| $I_{OH}$ | High-level output current | $V_{CC}$ = 1.65 V | | –4 | mA |
| | | $V_{CC}$ = 2.3 V | | –12 | |
| | | $V_{CC}$ = 2.7 V | | –12 | |
| | | $V_{CC}$ = 3 V | | –24 | |
| $I_{OL}$ | Low-level output current | $V_{CC}$ = 1.65 V | | 4 | mA |
| | | $V_{CC}$ = 2.3 V | | 12 | |
| | | $V_{CC}$ = 2.7 V | | 12 | |
| | | $V_{CC}$ = 3 V | | 24 | |
| $\Delta t/\Delta v$ | Input transition rise or fall rate | | | 10 | ns/V |
| $T_A$ | Operating free-air temperature | | –40 | 85 | °C |

NOTE 4: All unused control inputs of the device must be held at $V_{CC}$ or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | | $V_{CC}$ | MIN | TYP† | MAX | UNIT |
|---|---|---|---|---|---|---|---|---|
| $V_{OH}$ | | $I_{OH}$ = –100 µA | | 1.65 V to 3.6 V | $V_{CC}$–0.2 | | | V |
| | | $I_{OH}$ = –4 mA | | 1.65 V | 1.2 | | | |
| | | $I_{OH}$ = –6 mA | | 2.3 V | 2 | | | |
| | | $I_{OH}$ = –12 mA | | 2.3 V | 1.7 | | | |
| | | | | 2.7 V | 2.2 | | | |
| | | | | 3 V | 2.4 | | | |
| | | $I_{OH}$ = –24 mA | | 3 V | 2 | | | |
| $V_{OL}$ | | $I_{OL}$ = 100 µA | | 1.65 V to 3.6 V | | | 0.2 | V |
| | | $I_{OL}$ = 4 mA | | 1.65 V | | | 0.45 | |
| | | $I_{OL}$ = 6 mA | | 2.3 V | | | 0.4 | |
| | | $I_{OL}$ = 12 mA | | 2.3 V | | | 0.7 | |
| | | | | 2.7 V | | | 0.4 | |
| | | $I_{OL}$ = 24 mA | | 3 V | | | 0.55 | |
| $I_I$ | | $V_I$ = $V_{CC}$ or GND | | 3.6 V | | | ±5 | µA |
| $I_{I(hold)}$ | | $V_I$ = 0.58 V | | 1.65 V | 25 | | | µA |
| | | $V_I$ = 1.07 V | | 1.65 V | –25 | | | |
| | | $V_I$ = 0.7 V | | 2.3 V | 45 | | | |
| | | $V_I$ = 1.7 V | | 2.3 V | –45 | | | |
| | | $V_I$ = 0.8 V | | 3 V | 75 | | | |
| | | $V_I$ = 2 V | | 3 V | –75 | | | |
| | | $V_I$ = 0 to 3.6 V‡ | | 3.6 V | | | ±500 | |
| $I_{OZ}$ | | $V_O$ = $V_{CC}$ or GND | | 3.6 V | | | ±10 | µA |
| $I_{CC}$ | | $V_I$ = $V_{CC}$ or GND, | $I_O$ = 0 | 3.6 V | | | 40 | µA |
| $\Delta I_{CC}$ | | One input at $V_{CC}$ – 0.6 V, | Other inputs at $V_{CC}$ or GND | 3 V to 3.6 V | | | 750 | µA |
| $C_i$ | Control inputs | $V_I$ = $V_{CC}$ or GND | | 3.3 V | | 3.5 | | pF |
| | Data inputs | | | | | 6 | | |
| $C_o$ | Outputs | $V_O$ = $V_{CC}$ or GND | | 3.3 V | | 7 | | pF |

† All typical values are at $V_{CC}$ = 3.3 V, $T_A$ = 25°C.
‡ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

## timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)

| | | | $V_{CC}$ = 1.8 V | | $V_{CC}$ = 2.5 V ± 0.2 V | | $V_{CC}$ = 2.7 V | | $V_{CC}$ = 3.3 V ± 0.3 V | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| $f_{clock}$ | Clock frequency | | | § | | 150 | | 150 | | 150 | MHz |
| $t_w$ | Pulse duration, CLK high or low | | § | | 3.3 | | 3.3 | | 3.3 | | ns |
| $t_{su}$ | Setup time | Data before CLK↑ | § | | 4 | | 3.6 | | 3.1 | | ns |
| | | $\overline{\text{CLKEN}}$ before CLK↑ | § | | 3.4 | | 3.1 | | 2.7 | | |
| $t_h$ | Hold time | Data after CLK↑ | § | | 0 | | 0 | | 0 | | ns |
| | | $\overline{\text{CLKEN}}$ after CLK↑ | § | | 0 | | 0 | | 0 | | |

§ This information was not available at the time of publication.

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)**

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | $V_{CC}$ = 1.8 V | | $V_{CC}$ = 2.5 V ± 0.2 V | | $V_{CC}$ = 2.7 V | | $V_{CC}$ = 3.3 V ± 0.3 V | | UNIT |
|---|---|---|---|---|---|---|---|---|---|---|---|
| | | | MIN | TYP | MIN | MAX | MIN | MAX | MIN | MAX | |
| $f_{max}$ | | | † | | 150 | | 150 | | 150 | | MHz |
| $t_{pd}$ | CLK | Q | | † | 1 | 5.6 | 1 | 5.1 | 1 | 4.3 | ns |
| $t_{en}$ | $\overline{OE}$ | Q | | † | 1 | 6.1 | 1 | 5.8 | 1 | 4.8 | ns |
| $t_{dis}$ | $\overline{OE}$ | Q | | † | 1 | 5.5 | 1 | 4.7 | 1 | 4.4 | ns |

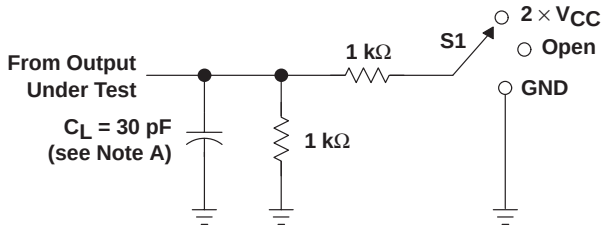
† This information was not available at the time of publication.

**operating characteristics, $T_A$ = 25°C**

| PARAMETER | | TEST CONDITIONS | $V_{CC}$ = 1.8 V | $V_{CC}$ = 2.5 V | $V_{CC}$ = 3.3 V | UNIT |
|---|---|---|---|---|---|---|
| | | | TYP | TYP | TYP | |
| $C_{pd}$ Power dissipation capacitance | Outputs enabled | $C_L$ = 50 pF, f = 10 MHz | † | 55 | 59 | pF |
| | Outputs disabled | | † | 46 | 49 | |

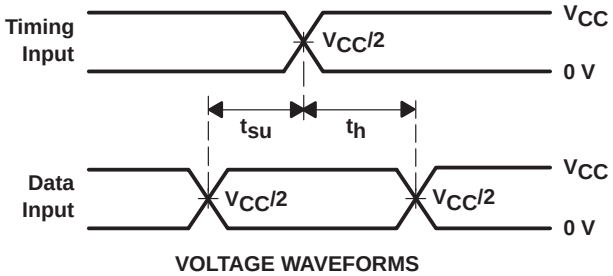
† This information was not available at the time of publication.

## PARAMETER MEASUREMENT INFORMATION
## $V_{CC}$ = 1.8 V

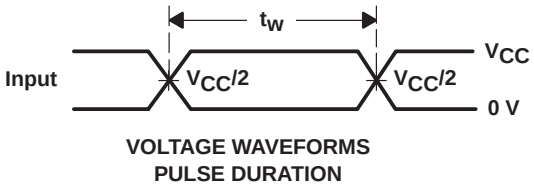



LOAD CIRCUIT

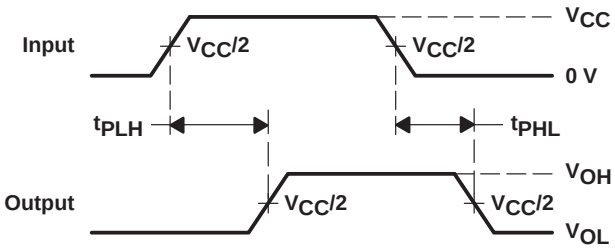
| TEST | S1 |
|---|---|
| $t_{pd}$<br>$t_{PLZ}/t_{PZL}$<br>$t_{PHZ}/t_{PZH}$ | Open<br>2 × $V_{CC}$<br>GND |



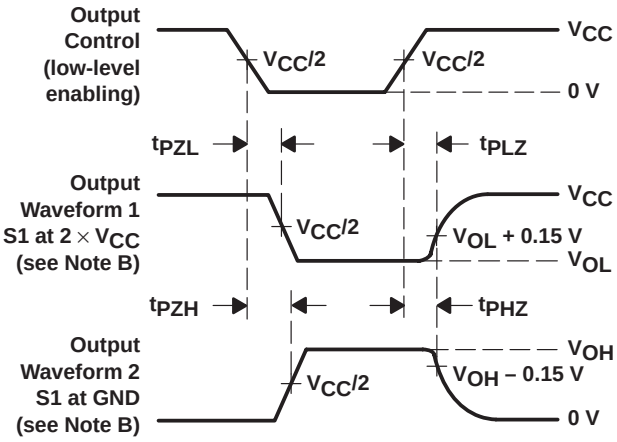

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PULSE DURATION




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES

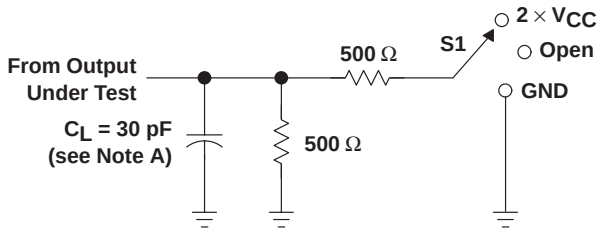



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ ≤ 2 ns, $t_f$ ≤ 2 ns.
D. The outputs are measured one at a time with one transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

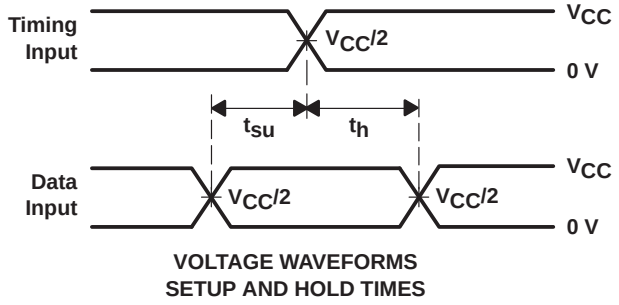
**Figure 1. Load Circuit and Voltage Waveforms**

## PARAMETER MEASUREMENT INFORMATION
## $V_{CC}$ = 2.5 V ± 0.2 V

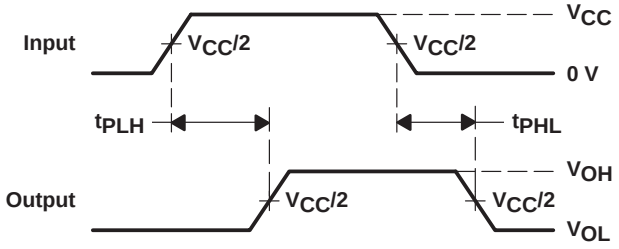



LOAD CIRCUIT

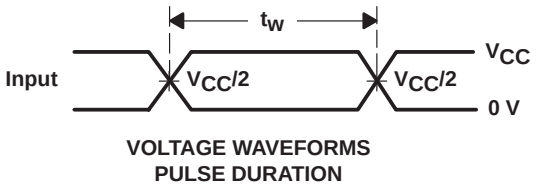
| TEST | S1 |
|---|---|
| $t_{pd}$<br>$t_{PLZ}/t_{PZL}$<br>$t_{PHZ}/t_{PZH}$ | Open<br>2 × $V_{CC}$<br>GND |



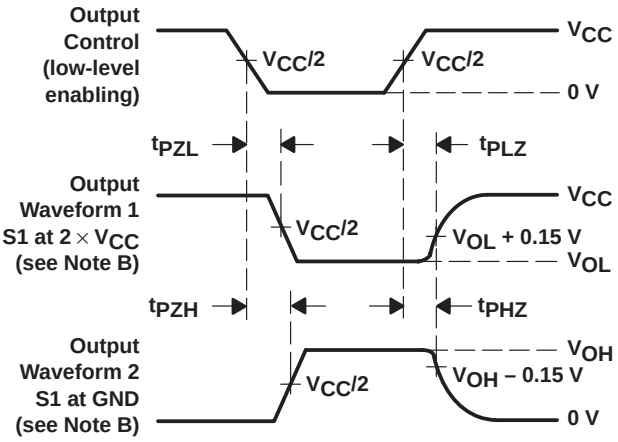

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES




VOLTAGE WAVEFORMS
PULSE DURATION

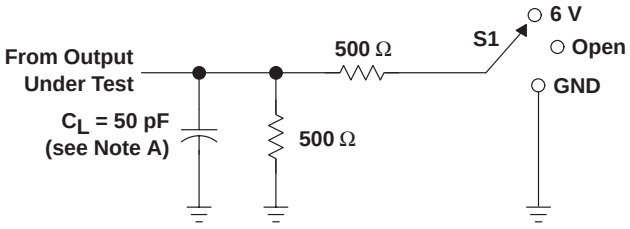



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, $Z_O$ = 50 Ω, $t_r$ ≤ 2 ns, $t_f$ ≤ 2 ns.
D. The outputs are measured one at a time with one transition per measurement.
E. $t_{PLZ}$ and $t_{PHZ}$ are the same as $t_{dis}$.
F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

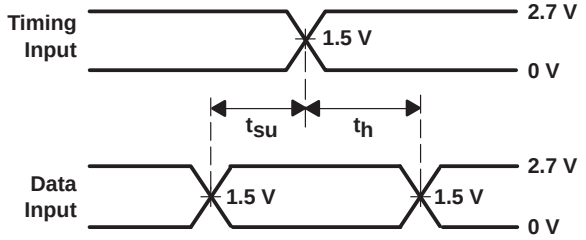
**Figure 2. Load Circuit and Voltage Waveforms**

## PARAMETER MEASUREMENT INFORMATION
## $V_{CC}$ = 2.7 V AND 3.3 V ± 0.3 V

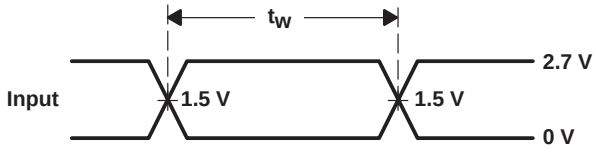



| TEST | S1 |
|---|---|
| $t_{pd}$ | Open |
| $t_{PLZ}/t_{PZL}$ | 6 V |
| $t_{PHZ}/t_{PZH}$ | GND |

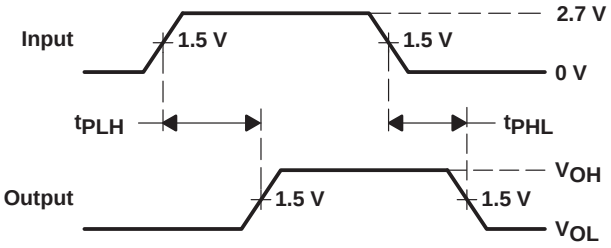
LOAD CIRCUIT



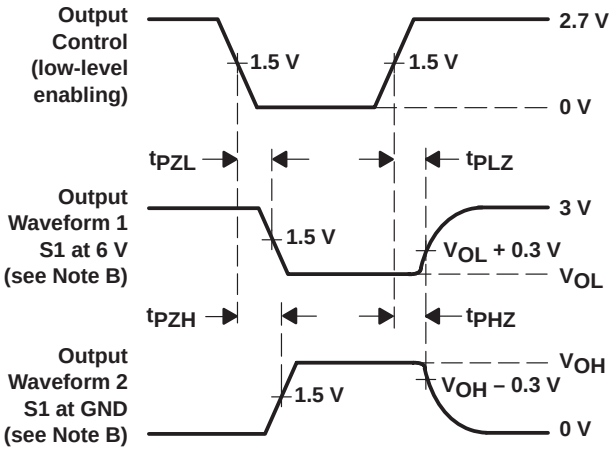

VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES




VOLTAGE WAVEFORMS
PULSE DURATION




VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES




VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. $C_L$ includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
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F. $t_{PZL}$ and $t_{PZH}$ are the same as $t_{en}$.
G. $t_{PLH}$ and $t_{PHL}$ are the same as $t_{pd}$.

**Figure 3. Load Circuit and Voltage Waveforms**

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